

POWER DIODE MODULE

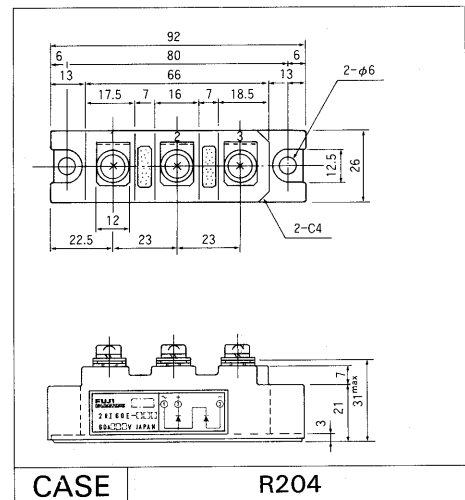
Features

- All the terminals and the mounting plate are electrically isolated. These modules can be installed in the same cooling fin as other modules, thus saving installation space – a cost-effective feature.
- The diode chips are coated with a glass of zinc oxide, making them highly resistant to temperature and humidity variation.
- Two diodes chips are connected in series internally, so allowing the rectifying circuit to be simplified.

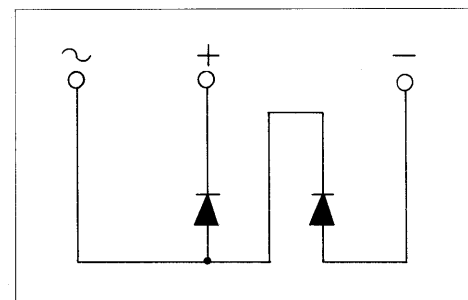
Applications

- Inverters for AC motors
- Power supply units for DC motors
- DC power supply units for battery chargers
- General purpose DC power supply units

Outline Drawings



Inner Circuit Schematic



Maximum Ratings and Characteristics

Absolute Maximum Ratings

| Items | Symbols | Conditions | 2RI60E | | Units |
|-------------------------------------|-------------|--|---------------|------|----------------------|
| | | | -060 | -080 | |
| Repetitive peak reverse voltage | V_{RRM} | | 600 | 800 | V |
| Non-repetitive peak reverse voltage | V_{RSM} | | 660 | 880 | V |
| Average forward current | $I_{F(AV)}$ | 50/60 Hz Sinewave, $T_C = 103^\circ\text{C}$ | 60×2 | | A |
| Surge current | I_{FSM} | Rated load conditions | 1200 | | A |
| I^2_t | I^2_t | Rated load conditions | 6000 | | A^2s |
| Junction temperature | T_j | | -40~+150 | | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | | -40~+150 | | $^\circ\text{C}$ |
| Tightening torque | | Mounting screw: M5 | 25±5 | | kg·cm |
| Vibration resistance | | | 5 | | G |
| Dielectric strength | | Between terminals and base | 2000 VAC 1min | | |
| Net. Weight | | | 180 | | g |

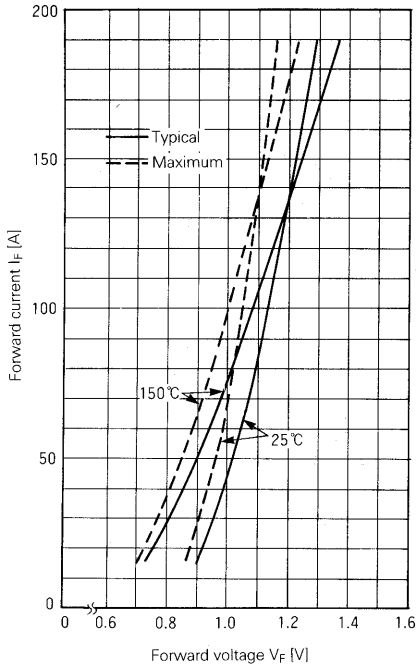
Electrical Characteristics

| Items | Symbols | Conditions | Min | Typ | Max | Units |
|-----------------|-----------|--|-----|-----|------|-------|
| Forward voltage | V_{FM} | $T_j = 25^\circ\text{C}$, $I_{FM} = 190\text{ A}$ | | | 1.30 | V |
| Reverse current | I_{RRM} | $T_j = 150^\circ\text{C}$, $V_R = V_{RRM}$ | | | 20 | mA |

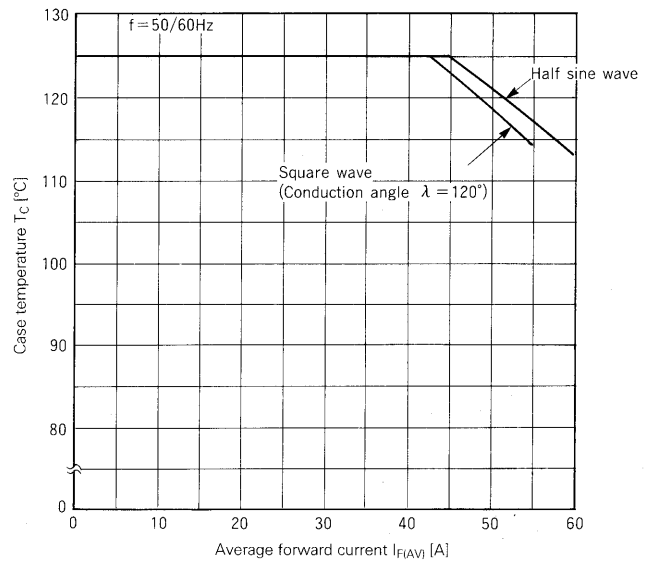
Thermal Characteristics

| Items | Symbols | Conditions | Min | Typ | Max | Units |
|---------------------------------------|---------------|--|-----|-----|------|---------------------------|
| Thermal resistance (Junction to case) | $R_{th(j-c)}$ | 50/60 Hz Sinewave, Thermal resistance for total loss | | | 0.25 | $^\circ\text{C}/\text{W}$ |
| Thermal resistance | $R_{th(c-f)}$ | With thermal compound | | | 0.10 | $^\circ\text{C}/\text{W}$ |

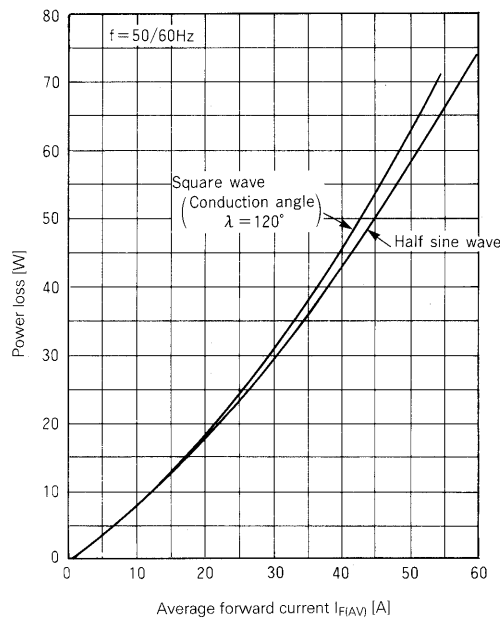
■ Characteristic curves



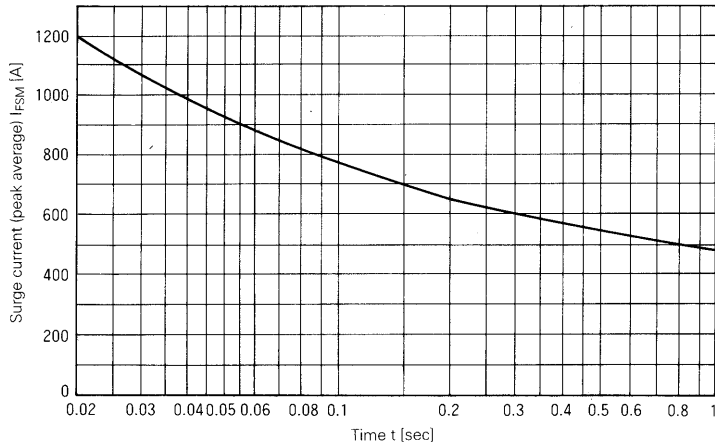
Forward Characteristics



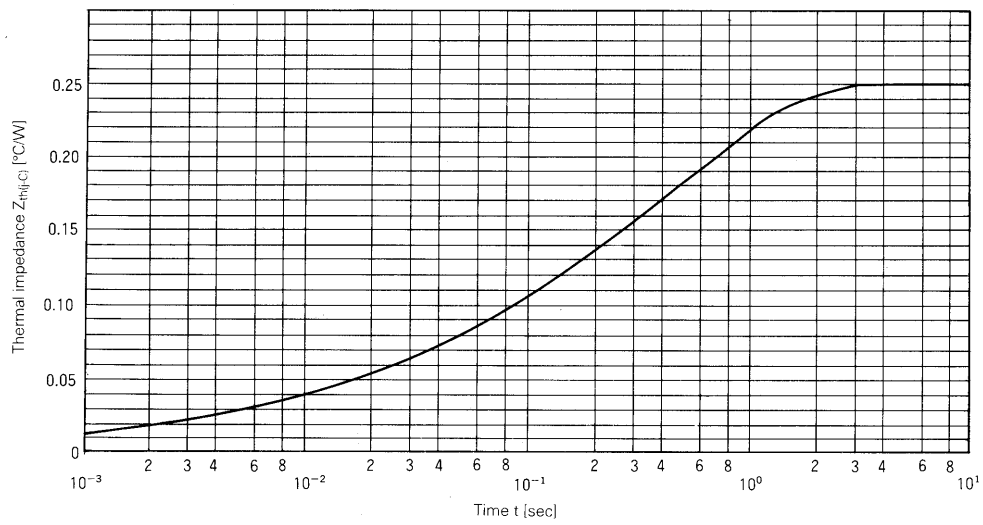
Case Temperature-Forward Average Current



Power Loss-Average Forward Current



Surge Current



Transient Thermal Impedance

For more information, contact:

Collmer Semiconductor, Inc.

P.O. Box 702708

Dallas, TX 75370

972-733-1700

972-381-9991 Fax

<http://www.collmer.com>